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## A Persistent 1,2-Dihydrophosphasilene Adduct

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Dedicated to Professor Herbert W. Roesky on the occasion of his 80th birthday

Abstract: The reaction of the arylchlorosilylene–NHC adduct ArSi(NHC)Cl  $[Ar = 2,6-Trip_2-C_6H_3;$  $NHC = (MeC)_2$ - $(NMe)_2C$ ] 1 with one molar equiv of LiPH<sub>2</sub> dme (dme = 1,2-1)dimethoxyethane) affords the first 1,2-dihydrophosphasilene adduct 2 (ArSi(NHC)(H)=PH). The latter is labile in solution and can undergo head-to-tail dimerization to give [ArSi-(H)PH]<sub>2</sub> 3 and "free" NHC. Further stabilization of 2 by complexation with  $\{W(CO)_5\}$  affords the isolable 1,2-dihydrophosphasilene-tungsten complex 4 [ArSi(NHC)(H)=P(H)W-(CO)<sub>5</sub>]. Additionally, the new 1-silyl-2-hydrophosphasilene  $ArSi(NHC)(H)=PSiMe_3$  5 could be synthesized and structurally characterized. DFT studies confirmed that the Si=P bond in 2 and 4 is mostly zwitterionic with drastically decreased double-bond character.

The parent phosphasilene H<sub>2</sub>Si=PH has not been isolated and was only observed some years ago in a matrix-spectroscopic study through the reaction of atomic silicon with phosphane.<sup>[1]</sup> If one compares different isomers with the formula H<sub>3</sub>SiP, the generated parent phosphasilene H<sub>2</sub>Si=PH in an argon matrix at 10 K is the most stable isomer, as calculations have suggested. [2-4] Spectroscopic evidence for the first stable phosphasilene with a Si=P bond with bulky aryl substituents at the phosphorus and silicon atoms was reported 30 years ago by Bickelhaupt et al.<sup>[5]</sup> Since then, several further species bearing a Si=P moiety have been reported. These species and related low-valent Group 14 compounds are stabilized either by taking advantage of steric congestion through the presence of bulky substituents and/or by pushpull electronic effects. [6-27] Only recently, the first isolable "half-parent" phosphasilenes  $\mathbf{I}_{1}^{[28]}\mathbf{II}_{2}^{[29,30]}$  and  $\mathbf{III}^{[31]}$  of the type  $R_2Si=PH$  or R(H)Si=PR could be realized (Scheme 1). However, a 1,2-dihydrophosphasilene IV with hydrogen

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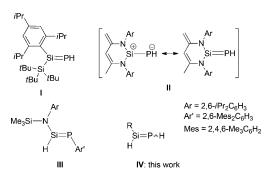
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**Scheme 1.** Phosphasilenes bearing a hydrogen atom at the Si and/or P center. Compounds of type **IV** are currently unknown.

atoms at silicon and phosphorus R(H)Si=PH, which are closer to the parent system, has not been reported to date.

In contrast, isolable 1,2-dihydrodisilene derivatives have been known since 2001. [32] In 2002, Tokitoh and co-workers reported the successful isolation of a 1,2-dihydrodisilene, which is kinetically stabilized by very bulky aryl groups. [33] Apparently, 1,2-dihydrophosphasilenes are more difficult to realize because of the marked polarity of the Si=P bond induced by the higher electronegativity of phosphorus versus silicon and because of the absence of steric bulk at the phosphorus center. [10,12]

Herein we report the synthesis of the first 1,2-dihydrophosphasilene adduct and the isolation and structural characterization of its  $R(H)Si=P(H)\rightarrow W(CO)_5$  complex. Furthermore, through the use of the same ligand at the silicon center, a 1-silyl-2-hydrophosphasilene could be prepared and fully characterized.

The reaction of the NHC adduct of arylchlorosilylene<sup>[34]</sup> 1 with one molar equiv of  $LiPH_2$  dme (dme = 1,2-dimethoxyethane) at room temperature in THF afforded, after 18 h, the 1,2-dihydrophosphasilene 2, presumably through tautomerization of its elusive phosphanylsilylene isomer (Scheme 2). The <sup>31</sup>P NMR spectrum of **2** shows a doublet of doublets with <sup>29</sup>Si satellites at  $\delta(^{31}P) = -301.4 \text{ ppm}$  ( $^{1}J(P,H) = 132.0 \text{ Hz}$ ,  $^{2}J(P,H) = 11.3 \text{ Hz}$ ,  $^{1}J(Si,P) = 120.7 \text{ Hz}$ ). The  $^{1}J(P,H)$  coupling constant is 12 Hz smaller than that of the Me<sub>4</sub>-NHC-stabilized form of **II** (NHC-**II**), [30] indicating lower 3s character of the P-H bond. The <sup>31</sup>P signal of **2** is shifted to higher field compared with the resonance of NHC-II ( $\delta$ (<sup>31</sup>P) = -259.8 ppm) and is even more shielded than signals of existing "half-parent" phosphasilenes. The upfield-shifted <sup>29</sup>Si signal  $(\delta(^{29}Si) =$ -25.6 ppm,  ${}^{1}J(Si,P) = 120.7$  Hz) is similar to the  ${}^{29}Si$  resonance signal of **III**  $(\delta(^{29}\text{Si}) = -21.1 \text{ ppm}).^{[31]}$  In the <sup>1</sup>H NMR spectrum the signal for the hydrogen nucleus at the phos-



Scheme 2. Synthesis of the 1,2-dihydrophosphasilenes 2 and 4 and dimer 3.

phorus appears at  $\delta = -1.38$  ppm and is split into a doublet of doublets ( ${}^{1}J(P,H) = 132.0$  Hz,  ${}^{3}J(H,H) = 5.8$  Hz). The Si–H signal with  ${}^{29}Si$  satellites is split into a doublet of doublet as well and can be found at  $\delta = 5.95$  ppm ( ${}^{1}J(Si,H) = 192.8$  Hz,  ${}^{2}J(P,H) = 11.3$  Hz,  ${}^{3}J(H,H) = 5.8$  Hz).

Unfortunately, 1,2-dihydrophosphasilene is relatively labile in solution. In an NMR-scale experiment, the decomposition of  $\bf 2$  in [D<sub>8</sub>]THF at room temperature is relatively slow but at 50 °C it takes only a few hours. Single crystals of the head-to-tail dimer  $\bf 3$  suitable for X-ray diffraction analysis could be obtained from the decomposition mixture in concentrated n-hexane solutions upon storage at 7 °C. Regrettably, its structure cannot be discussed due to poor crystal quality. The high-resolution atmospheric-pressure chemical ionization mass spectrum (HR-APCI-MS) clearly proves the composition of  $\bf 3$ .

In fact, density functional theory (DFT) calculations indicate that the formation of **3**, under the loss of the NHC donor, is thermodynamically slightly favorable by  $\Delta G = -5.7 \text{ kcal mol}^{-1}$ . For a consecutive path in which the NHC is first removed, the Gibbs free energy of activation is  $\Delta G^{\sharp} = 16.9 \text{ kcal mol}^{-1}$ . In contrast, for a concerted mechanism, the Gibb free energy of the transition state is  $\Delta G^{\sharp} = 12.1 \text{ kcal mol}^{-1}$ . These results imply that the formation of the dimer can occur even at room temperature.

Furthermore, DFT studies at the B97-D/6-31G(d) level of theory were performed to elucidate the bonding situation in **2** and in its NHC-free form **2**′ (Table 1). The Wiberg bond index (WBI) of the Si–P bond of donor-free 1,2-dihydrophosphasilene ArSi(H)=PH (**2**′; Ar = 2,6-Trip<sub>2</sub>-C<sub>6</sub>H<sub>3</sub>) is 1.83. The natural bond orbital (NBO) analysis shows that the Si–P moiety has  $\sigma$  and  $\pi$  bonds. Compared to the "half-parent" phosphasilene **II** the s character of the  $\sigma$  bond of the silicon center is lower and shows sp² hybridization (36.8 % s, 62.7 % p, 0.4 % d; for **II**: 64.6 % s, 35.1 % p, 0.3 % d). The  $\pi$  bond is polarized to 63 % towards the phosphorus atom and exhibits only p character. The Si–P bond in the NHC-stabilized 1,2-dihydrophosphasilene **2** has a reduced WBI of 1.26 which is even lower than that of NHC-**II** (1.34). The calculated Si–P

**Table 1:** Calculated Si–P distances [pm], WBI values, atomic charges, and NRT analysis of the Si=P bond in  $H_2Si=PH$ ,  $H_2Si(NHC)=PH$ , ArSi(H)=PH (Ar=2,6-Trip<sub>2</sub>-C<sub>6</sub>H<sub>3</sub>; NHC=(MeC)<sub>2</sub>(NMe)<sub>2</sub>C), **2**, and **4**.

Compound	d(Si–P) [pm]	WBI	Charges	NRT
H <sub>2</sub> Si=PH	209.6	1.97	Si: +0.58 P: -0.29	Si=P: 100%
H <sub>2</sub> Si(NHC)=PH	217.1	1.29	Si: +0.74 P: -0.62	Si-P: 76.3% Si-P: 23.7%
ArSi(H)=PH (2')	210.6	1.83	Si: +0.85 P: -0.32	Si-P: 3.9% Si=P: 96.1%
2	217.5	1.26	Si: +1.05 P: -0.60	Si-P: 78.9% Si=P: 21.1%
4	221.7	1.09	Si: +1.11 P: -0.20	Si-P: 89.9% Si=P: 10.1%

bond length in **2** equals 217.5 pm and is 7 pm larger than that in the NHC-free 1,2-dihydrophosphasilene (d(Si,P) = 210.6 pm). An optimized molecular structure of compound **2** is shown is in Figure 1. The NBO analysis indicated only one

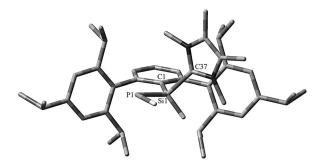


Figure 1. Stick model of the DFT-derived molecular structure of 2. Hydrogen atoms, except for those on Si1 and P1, have been omitted for clarity.

σ-type bond between the Si and P atoms and two lone pairs residing on the phosphorus center. The NPA charges (Si: +1.05; P: -0.60) and the natural resonance theory (NRT) analysis (Si–P: 78.9%, Si=P: 21.1%) reflect this bonding situation. These computational results and the high-field-shifted <sup>31</sup>P resonance suggest that the zwitterionic resonance structure **2B** is the dominant contribution to the electronic features of **2** (Scheme 3).

Scheme 3. Resonance forms 2A and 2B.

These differences in the Si-P bonding situation can also be observed in the parent compounds H<sub>2</sub>Si=PH and H<sub>2</sub>Si-(NHC)=PH (Table 1). Here, the Si-P bond length in the



donor-free compound is greater than that in the NHCstabilized phosphasilene by 7.5 pm. The WBI is almost 2 for H<sub>2</sub>Si=PH but merely 1.29 for H<sub>2</sub>Si(NHC)=PH. The NBO analysis shows, compared to the parent compound, that the Si-P bond in H<sub>2</sub>Si(NHC)=PH consists only of a σ-type bond between the Si and P atoms and two lone pairs residing on the phosphorus center. As the atomic charges affirm, the Si–P σbond in the NHC-stabilized form is strongly polarized towards the phosphorus center. The NRT analysis reveals that in the parent phosphasilene the resonance structure with a Si=P bond is the main form, whereas in H<sub>2</sub>Si(NHC)=PH, a resonance structure with a Si-P single bond is the major form (76.3%).

To stabilize the 1,2-dihydrophosphasilene, compound 2 was treated with freshly prepared [W(CO)<sub>5</sub>thf] (Scheme 2), affording the desired 1,2-dihydrophosphasilene-tungsten complex 4 in good yields. The <sup>31</sup>P{<sup>1</sup>H} signal with <sup>183</sup>W satellites is shifted 13 ppm to higher field  $(\delta(^{31}P) =$ -314.0 ppm,  ${}^{1}J(W,P) = 71.8 \text{ Hz}$ ). However, in the  ${}^{1}H \text{ NMR}$ spectrum the doublet of the P-H signal is shifted to lower field ( $\delta = -0.65$  ppm). The  ${}^{1}J(P,H)$  coupling constant increased by 62.4 Hz, which is typical for complexes where the phosphorus binds to a σ-acceptor such as a transition metal. [36] The 29Si{1H} NMR spectrum displays a doublet at  $\delta(^{29}\text{Si}) = -22.1 \text{ ppm } (^{1}J(\text{Si},\text{P}) = 79.0 \text{ Hz}). \text{ The } ^{1}J(\text{Si},\text{P}) \text{ cou-}$ pling constant decreased by 42 Hz, indicating reduced Si=P bond character.

The molecular structure of 4 has been confirmed by X-ray diffraction analysis (Figure 2). The Si1-P1 distance of 221.05(4) pm, which is in a good agreement with the calculated Si-P distance (Table 1), is much longer than those found in NHC-III and in other structurally characterized phosphasilenes (ca. 205.3-216.5 pm) and is in the typical range of Si-P single bonds (average 225 pm).[31] The WBI of

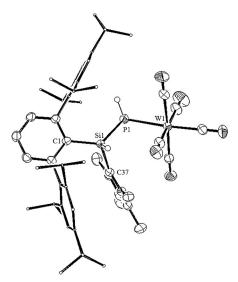


Figure 2. ORTEP representation of the molecular structure of 4. Thermal ellipsoids at 50% probability; hydrogen atoms, except for those on Si1 and P1, have been omitted for clarity. Selected distances (pm) and angles (°) of 4: Si1-P1 221.05(14), Si1-C1 191.11(4), Si1-C37 192.1(4), P1-W1 263.65(10); C1-Si1-P1 122.50(12), C37-Si1-P1 98.78(12), Si1-P1-W1 105.59(5).

the Si1-P1 bond is only 1.09 and NRT analysis indicates that a zwitterionic resonance form similar to 2B is the most important structure of 4.

The IR spectrum of 4 displays two weak bands at  $v_{PH}$  = 2322 cm<sup>-1</sup> and  $\nu_{\rm SiH} = 2170$  cm<sup>-1</sup> corresponding to the stretching vibration of the PH and SiH groups, respectively. The characteristic stretching vibrations of the CO ligands are located at  $\nu_{\rm CO} = 2044$ , 1948, 1893, and 1852 cm<sup>-1</sup>.

The reaction of 1 and LiP(SiMe<sub>3</sub>)<sub>3</sub> results in the new 1silyl-2-hydrophosphasilene 5, which could be isolated and fully characterized. The yield of 5 could be improved by adding one molar equivalent of bis(trimethylsilyl)phosphane to the reaction mixture, leading to full conversion of 1 to 5 (Scheme 4). The <sup>31</sup>P NMR spectrum of the reaction mixture

Scheme 4. Synthesis of the 2-hydrophosphasilene 5.

reveals, beside the signal for the product at high field  $(\delta(^{31}P) = -331.7 \text{ ppm})$ , the signal corresponding to  $P(SiMe_3)_3$ at  $\delta(^{31}P) = -253.4$  ppm. It is known that HPR<sub>2</sub> compounds are able to disproportionate into H<sub>2</sub>PR and PR<sub>3</sub>.<sup>[37]</sup> Therefore we propose that 1 reacts with the in situ formed H<sub>2</sub>P(SiMe<sub>3</sub>), affording the corresponding NHC adduct of the phosphanylsilylene Ar(NHC)SiP(H)SiMe<sub>3</sub>, which undergoes tautomerization to 5. This proposed mechanism is supported by the clean reaction of 1 with H<sub>2</sub>P(SiMe<sub>3</sub>) in the presence of Et<sub>3</sub>N as a base.[35]

The <sup>29</sup>Si<sup>1</sup>H NMR spectrum of 5 shows two doublets at  $\delta(^{29}\text{Si}) = -27.5 \text{ ppm (Si=P, }^{1}\text{J(Si,P)} = 130.8 \text{ Hz) and } \delta(^{29}\text{Si}) =$ 1.65 ppm (SiMe<sub>3</sub>,  ${}^{1}J(Si,P) = 71.5 \text{ Hz}$ ), respectively. The latter coupling constant is in the range typical for P-silyl-phosphasilenes.[10] Compared to the 1,2-dihydrophosphasilene 2, the <sup>1</sup>J(Si,P) coupling constant in 5 is increased by 10.1 Hz, indicating increased Si-P double-bond character. This effect has already been described for the parent phosphasilenes H<sub>2</sub>Si=PH and H<sub>2</sub>Si=P(SiH<sub>3</sub>). Computations show that the Si-P  $\pi$ -bond strength in the parent P-silyl-phosphasilene is increased and the Si-P bond length is shortened by hyperconjugation effects due to the silvl substituent at phosphorus.<sup>[12,30]</sup> The stronger σ-donor ability of the silyl group is also demonstrated by the upfield-shifted <sup>31</sup>P resonance signal in 5  $(\delta(^{31}P) = -331.7 \text{ ppm})$  compared to that in **2**  $(\delta(^{31}P) =$ -301.4 ppm).

The molecular structure of 5 can be found in the Supporting Information. The silicon center is four-coordinated and adopts a distorted tetrahedral geometry. The Si1-P1 bond length of 214.59(17) pm is in the range typical of Si=P and is shorter than the P1-Si2 (220.68(18) pm).



In summary, we have synthesized the first 1,2-dihydrophosphasilene adduct 2, which is labile in solution and slowly dimerizes to give 3. Compound 2 could be further stabilized by complexation of {W(CO)<sub>5</sub>} at the phosphorus atom to afford the 1,2-dihydrophosphasilene-tungsten complex 4. Additionally, the new 1-silyl-2-hydrophosphasilene 5 has been synthesized which, similar to the formation of 2, resulted from the tautomerization of the corresponding elusive phosphanylsilylene-NHC adduct.

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